

**2SA1677,
2SC4397**

2059

PNP/NPN Epitaxial Planar
Silicon Transistors

T-37-13

T-35-11

Switching Applications
(with Bias Resistances $R1=22k\Omega$, $R2=22k\Omega$)

©2765

Applications

- Switching circuit, inverter circuit, interface circuit, driver circuit

Features

- On-chip bias resistance ($R1=22k\Omega$, $R2=22k\Omega$)
- Very small-sized package permitting 2SA1677/2SC4397-applied sets to be made smaller and slimmer

():2SA1677

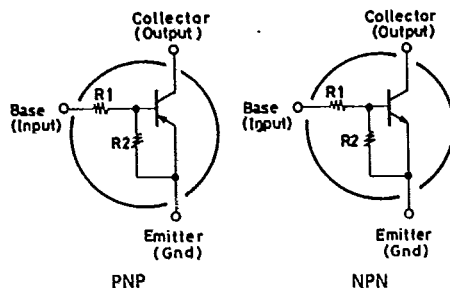
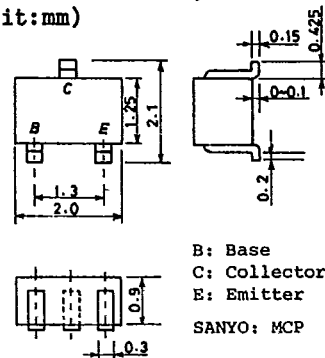
Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

			unit
Collector to Base Voltage	V_{CB0}	(-)50	V
Collector to Emitter Voltage	V_{CE0}	(-)50	V
Emitter to Base Voltage	V_{EB0}	(-)10	V
Collector Current	I_C	(-)100	mA
Peak Collector Current	i_{op}	(-)200	mA
Collector Dissipation	P_C	150	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a=25^\circ\text{C}$

			min	typ	max	unit
Collector Cutoff Current	I_{CBO}	$V_{CB}=(-)40\text{V}, I_E=0$			(-)0.1	μA
Collector Cutoff Current	I_{CEO}	$V_{CE}=(-)40\text{V}, I_E=0$			(-)0.5	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=(-)5\text{V}, I_C=0$	(-)70	(-)113	(-)150	μA
DC Current Gain	h_{FE}	$V_{CE}=(-)5\text{V}, I_C=(-)5\text{mA}$	50			
Gain-Bandwidth Product	f_T	$V_{CE}=(-)10\text{V}, I_C=(-)5\text{mA}$		250 (200)		MHz
Output Capacitance	c_{ob}	$V_{CB}=(-)10\text{V}, f=1\text{MHz}$		3.3 (5.1)		pF
C-E Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)10\text{mA}, I_E=(-)0.5\text{mA}$		(-)0.1	(-)0.3	V
C-B Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu\text{A}, I_E=0$	(-)50			V
C-E Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)100\mu\text{A}, R_{BE}=\infty$	(-)50			V
Input OFF-State Voltage	$V_{I(off)}$	$V_{CE}=(-)5\text{V}, I_C=(-)100\mu\text{A}$	(-)0.8	(-)1.1	(-)1.5	V
Input ON-State Voltage	$V_{I(on)}$	$V_{CE}=(-)0.2\text{V}, I_C=(-)5\text{mA}$	(-)1.0	(-)1.9	(-)3.0	V
Input Resistance	R_1		15	22	29	kohm
Resistance Ratio	$R1/R2$		0.9	1.0	1.1	

Marking 2SA1677:CL, 2SC4397:CY

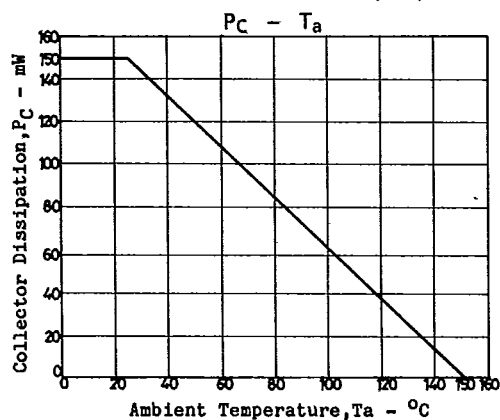
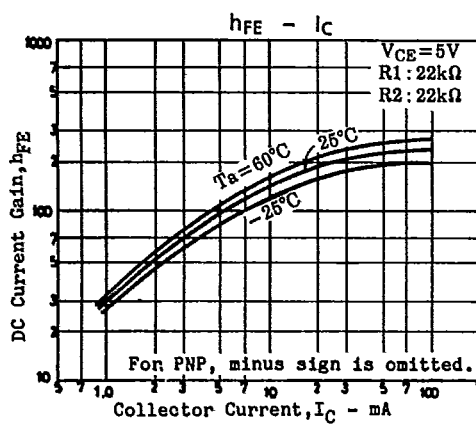
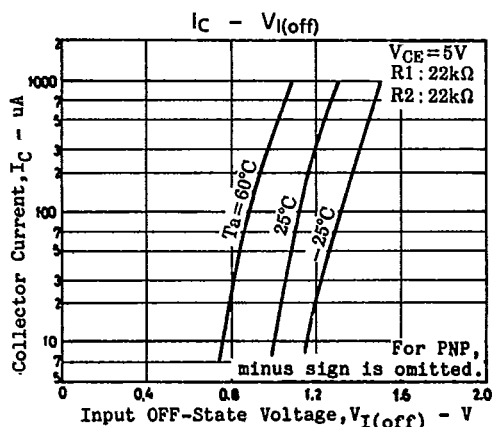
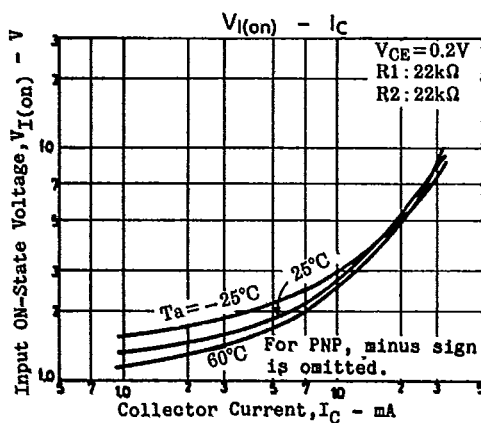
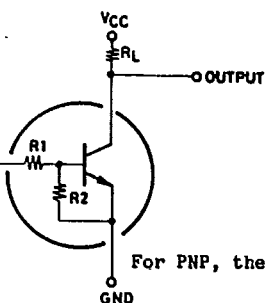
Electrical Connection**Case Outline 2059**
(unit:mm)

4118YT, TS No.2765-1/2

Sample Application Circuit

Input ON-State voltage: 3V or more

Input OFF-State voltage: 0.8V or less

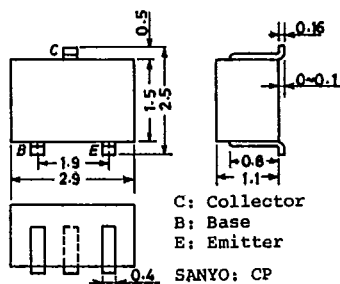


T-91-20

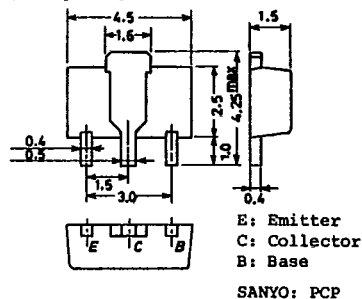
CASE OUTLINES OF SURFACE MOUNT TRANSISTORS

- All of Sanyo surface mount transistor case outlines are illustrated below.
- All dimensions are in mm, and dimensions which are not followed by min. or max. are represented by typical values.
- No marking is indicated.

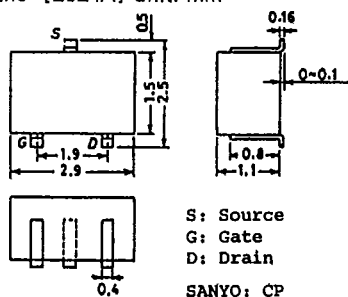
Case Outline—[2018A] unit: mm



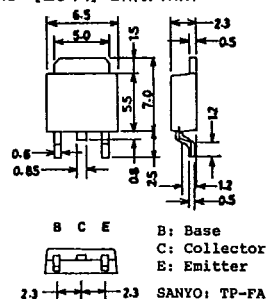
Case Outline—[2038] unit: mm



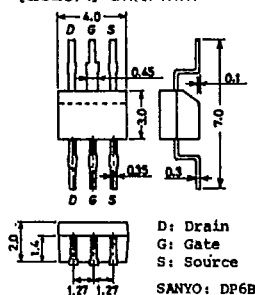
Case Outline—[2024A] unit: mm



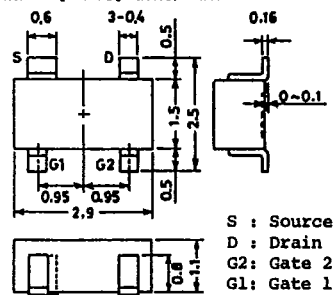
Case Outline—[2044] unit: mm



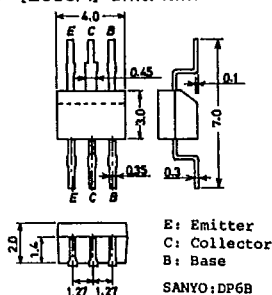
Case Outline—[2028A] unit: mm



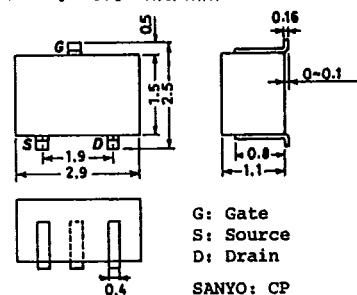
Case Outline—[2046] unit: mm



Case Outline—[2030A] unit: mm

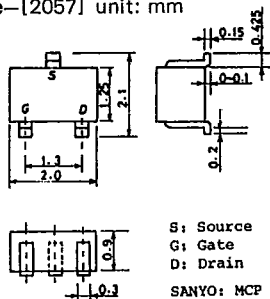


Case Outline—[2050] unit: mm

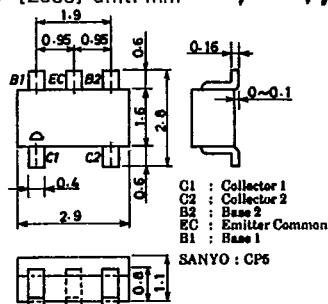


T-91-20

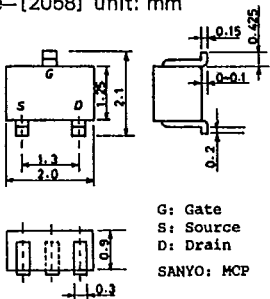
Case Outline—[2057] unit: mm



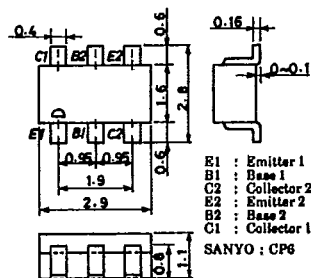
Case Outline—[2066] unit: mm



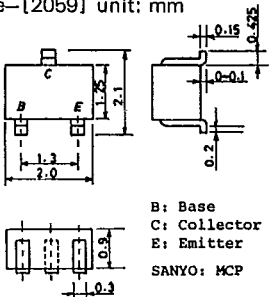
Case Outline—[2058] unit: mm



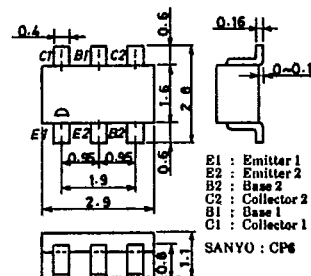
Case Outline—[2067] unit: mm



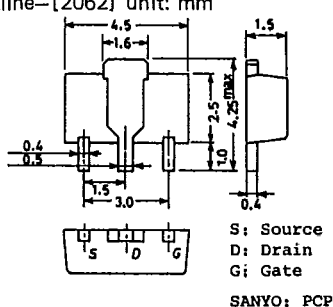
Case Outline—[2059] unit: mm



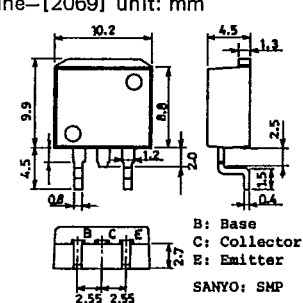
Case Outline—[2068] unit: mm



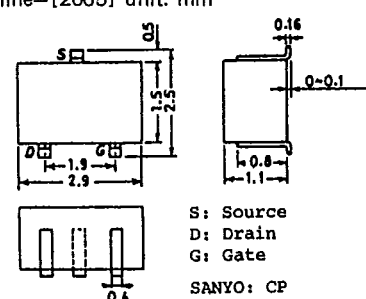
Case Outline—[2062] unit: mm



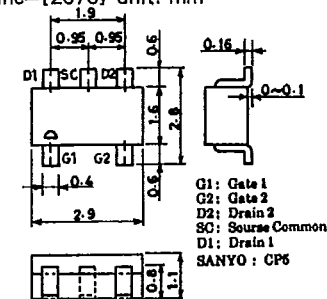
Case Outline—[2069] unit: mm



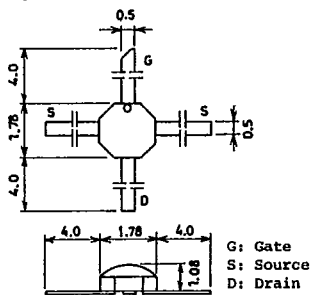
Case Outline—[2065] unit: mm



Case Outline—[2070] unit: mm

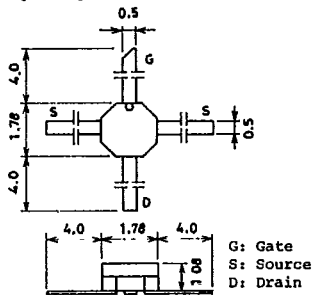


Case Outline-[2071] unit: mm



T-9120

Case Outline-[2072] unit: mm



Case Outline-[2073] unit: mm

